



74AHC595

8-BIT SHIFT REGISTER WITH 8-BIT OUTPUT REGISTER

Description

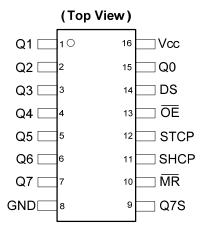
The 74AHC595 is an advanced high speed CMOS device.

An eight bit shift register accepts data from the serial input (DS) on each positive transition of the shift register clock (STCP). When asserted low the reset function (MR) sets all shift register values to zero and is independent of all clocks.

Data from the input serial shift register is placed in the output register with a rising pulse on the storages resister clock (SHCP). With the output enable (OE) asserted low the 3-state outputs Q0-Q7 become active and present.

All registers capture data on rising edge and change output on the falling edge. If both clocks are connected together, the input shift register is always one clock cycle ahead of the output register.

Pin Assignments



SO-16 / TSSOP-16

Features

- Wide Supply Voltage Range from 2.0 V to 5.5V
- Sinks or sources 8mA at V_{CC} = 4.5V
- CMOS low power consumption
- Schmitt Trigger Action at All Inputs
- Inputs Accept up to 5.5V
- ESD Protection Tested per JESD 22
 - Exceeds 200-V Machine Model (A115-A)
 - Exceeds 2000-V Human Body Model (A114-A)
 - Exceeds 1000-V Charged Device Model (C101C)
- Latch-Up Exceeds 250mA per JESD 78, Class II
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)

Applications

- General Purpose Logic
- Serial to Parallel Data conversion
- Capture and hold data for extended periods of time
- Allow simple serial bit streams from a microcontroller to control as many peripheral lines as needed
- Wide array of products such as:
 - Computer peripherals
 - **Appliances**
 - Industrial control

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- 2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green"
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

Click here for ordering information, located at the end of datasheet

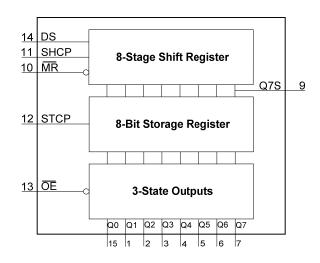
1 of 10 74AHC595 June 2013 © Diodes Incorporated Document number: DS35486 Rev. 3 - 2



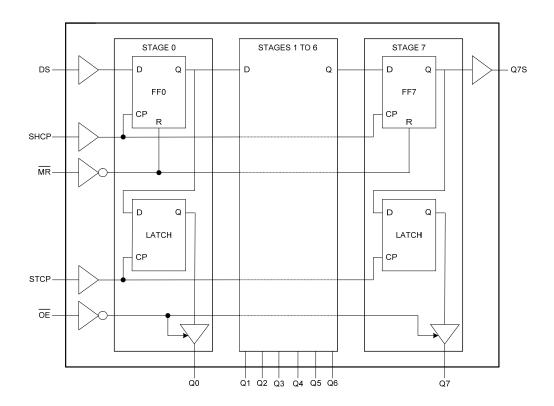
Pin Descriptions

Pin Number	Pin Name	Description
1	Q1	Parallel Data Output 1
2	Q2	Parallel Data Output 2
3	Q3	Parallel Data Output 3
4	Q4	Parallel Data Output 4
5	Q5	Parallel Data Output 5
6	Q6	Parallel Data Output 6
7	Q7	Parallel Data Output 7
8	GND	Ground
9	Q7S	Serial Data Output
10	MR	Master Reset Input
11	SHCP	Shift Register Clock Input
12	STCP	Storage Register Clock Input
13	ŌE	Output Enable Input
14	DS	Serial Data Input
15	Q0	Parallel Data Output 0
16	Vcc	Supply Voltage

Functional Diagram



Logic Diagram

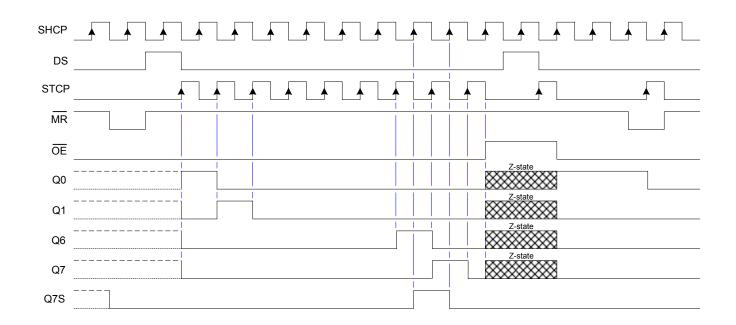




Functional Description and Timing Diagram

	Contr	rol		Input	Output		Firmation
SHCP	STCP	OE	MR	DS	Q7S	Qn	Function
Х	Х	L	L	-	L	NC	Low-level asserted on MR clears shift register. Storage register is unchanged
Х	↑	L	L	_	L	L	Empty shift register transferred to storage register
Х	Х	Н	L	_	L	Z	Shift register remains clear;: All Q ouputs in Z state.
↑	x	L	Н	-	Q6S	NC	HIGH is shifted into first stage of Shift Register Contents of each register shifted to next register The content of Q6S has been shifted to Q7S and now appears on device pin Q7S
Х	1	L	Н	-	NC	QnS	Contents of shift register copied to storage register. With output now in active state the storage resister contents appear on Q outputs.
↑	↑	L	Н	_	Q6S	QnS	

H=HIGH voltage state L=LOW voltage state ↑=LOW to HIGH transition X= don't care – high or low (not floating) NC= No change Z= high-impedance state





Absolute Maximum Ratings (Note 4) (@T_A = +25°C, unless otherwise specified.)

Symbol	Parameter	Rating	Unit
ESD HBM	Human Body Model ESD Protection	2	KV
ESD CDM	Charged Device Model ESD Protection	1	KV
ESD MM	Machine Model ESD Protection	200	V
Vcc	Supply Voltage Range	-0.5 to 7.0	V
VI	Input Voltage Range	-0.5 to 7.0	V
Vo	Voltage applied to output in high or low state	-0.3 to V _{CC} +0.5	V
I _{IK}	Input Clamp Current V _I < -0.5V	-20	mA
I _{OK}	Output Clamp Current V _O <-0.5V	-20	mA
I _{OK}	Output Clamp Current V _O > V _{CC} + 0.5V	25	mA
I _O	Continuous output current	+/- 25	mA
Icc	Continuous current through Vcc or GND	75	mA
I _{GND}	Continuous current through Vcc or GND	-75	mA
TJ	Operating Junction Temperature	-40 to 150	°C
T _{STG}	Storage Temperature	-65 to 150	°C
Ртот	Total Power Dissipation	500	mW

Note:

Recommended Operating Conditions (Note 5) (@TA = +25°C, unless otherwise specified.)

Symbol	Parameter	Conditions	Min	Max	Unit
V _{CC}	Supply Voltage	=	2.0	5.5	V
VI	Input Voltage	_	0	5.5	V
Vo	Output Voltage	Active Mode	0	V _{CC}	V
Δt/ΔV	Input transition Rise or Fall Rate	V _{CC} = 3.0V to 3.6V	-	100	ns/V
ΔυΔν	Input transition Rise of Fair Rate	V _{CC} = 4.5V to 5.5V	-	20	115/ V
T _A	Operating Free-Air Temperature	-	-40	+125	°C

Note:

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Symbol	Parameter	Test Conditions	Vcc	Т	_A = +25°	,C	$T_A = -40^{\circ}$	C to +85°C	$T_A = -40^{\circ}C$	to +125°C	Unit
Syllibol	Faranietei	rest Conditions	V CC	Min	Тур	Max	Min	Max	Min	Max	Oilit
	Link lavel lawy	=	2.0V	1.5	_	-	1.5	-	1.5	-	
V_{IH}	High-level Input Voltage	=	3.0V	2.1	_	-	2.1	-	2.1	-	V
	Voltage	=	5.5V	3.85	=	=	3.85	=	3.85	=	
	Low lovel input	=	2.0V	=	=	0.5	-	0.5	=	0.5	
V_{IL}	Low-level input voltage	=	3.0V	-	_	0.9	-	0.9	-	0.9	V
	voltage	=	5.5V	-	_	1.65	_	1.65	-	1.65	
		I _{OH} = -50μA	2.0V	1.9	2.0	-	1.9	-	1.9	-	
		I _{OH} = -50μA	3.0V	2.9	3.0	-	2.9	-	2.9	-	
VoH	High Level Output Voltage	I _{OH} = -50μA	4.5V	4.4	4.5	-	4.4	-	4.4	-	V
	Output Voltage	I _{OH} = -4mA	3.0V	2.58	_	-	2.48	-	2.40	-	
		I _{OH} = -8mA	4.5V	3.94	_	_	3.80	-	3.70	-	
		I _{OL} = 50μA	2.0V	-	0	0.1	_	0.1	-	0.1	V
	l	I _{OL} = 50μA	3.0V	-	0	0.1	_	0.1	-	0.1	
V_{OL}	Low-level Output Voltage	I _{OL} = 50μA	4.5V	-	0	0.1	-	0.1	=	0.1	
	Output voltage	I _{OL} = 4mA	3.0V	-	=	0.36	-	0.44	=	0.55	
		I _{OL} = 8mA	4.5V	-	=	0.36	_	0.44	-	0.55	
lı	Input Current	V_I = GND to 5.5V	5.5V	-	0.1	±0.1	-	±1	=	±2	μΑ
l _{OZ}	OFF-state output current	$V_I = V_{IH} \text{ or } V_{IL};$ $V_O = V_{CC} \text{ or GND}$	5.5V	-	-	±0.25	_	±2.5	_	±10	μΑ
Icc	Supply Current	$V_I = GND \text{ or } V_{CC} I_O = 0$	5.5V	-	-	4.0	-	40	-	80	μΑ
Ci	Input Capacitance	V _i = V _{CC} or GND	5.5V	=	4	10	=	10	=	10	pF

74AHC595Document number: DS35486 Rev. 3 - 2

^{4.} Stresses beyond the absolute maximum may result in immediate failure or reduced reliability. These are stress values and device operation should be within recommend values.

^{5.} Unused inputs should be held at $\ensuremath{V_{\text{CC}}}$ or Ground.



Switching Characteristics

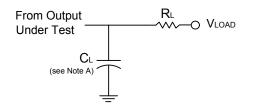
Symbol /	Pins	Took Conditions	.,	Т	A = +25°	С	-40°C to	o +85°C	-40°C to	+125°C	Unit			
Parameter	Pins	Test Conditions	V _{CC}	Min	Тур	Max	Min	Max	Min	Max	Unit			
f _{MAX}			3.0V to 3.6V	80	125	_	60	-	40	_				
Maximum Frequency	SHCP or STCP	Figure 2	4.5V to 5.5V	130	70	-	110	-	90	-	MHz			
	SHCP	Figure 2	3.0V to 3.6V	5.0	_	_	5.0	İ	5.0	_				
	HIGH or LOW	Figure 2	4.5V to 5.5V	5.0	_	_	5.0	İ	5.0	_				
t₩	STCP	Figure 2	3.0V to 3.6V	5.0	_	_	5.0	-	5.0	_	ns			
Pulse Width	HIGH or LOW	Figure 2	4.5V to 5.5V	5.0	_	_	5.0	-	5.0	_	115			
	MBLOW	Figure 2	3.0V to 3.6V	5.0	_	_	5.0	-	5.0	_				
	MR LOW	Figure 2	4.5V to 5.5V	5.0	_	_	5.0	_	5.0	_				
	DC to CLICD	Figure 2	3.0V to 3.6V	3.5	_	_	3.5	_	3.5	_	20			
tsu	DS to SHCP	Figure 2	4.5V to 5.5V	3.0	_	_	3.0	_	3.0	_	ns			
Set-up Time	CLICD to CTCD	Figure 2	3.0V to 3.6V	8.5	_	_	8.5	_	8.5	_	20			
	SHCP to STCP	Figure 2	4.5V to 5.5V	5.0	_	_	5.0	_	5.0	_	ns			
t _H	DC to CUCD	Fig 0	3.0V to 3.6V	1.5	_	_	1.5	_	1.5	_				
Hold Time	DS to SHCP	Figure 2	4.5V to 5.5V	2.0	=	_	2.0	=	2.0	_	ns			
trec		Figure 2	3.0V to 3.6V	3.0	_	_	3.0	_	3.0	_	20			
Recovery Time	MR to SHCP	MR to SHCP	MR to SHCP	MR to SHCP	Figure 2	4.5V to 5.5V	2.5	=	_	2.5	=	2.5	_	ns
		Figure 2	3.0V to 3.6V	_	5.7	13.0	1.0	15.0	1.0	16.5				
	SHCP to Q7S	$C_L = 15pF$	4.5V to 5.5V	_	4.0	8.2	1.0	9.4	1.0	10.5				
	SHCP 10 Q/S	Figure 2	3.0V to 3.6V	_	7.7	16.5	1.0	18.5	1.0	20.1	ns			
		$C_L = 50pF$	4.5V to 5.5V	_	5.4	10.0	1.0	11.4	1.0	12.5				
		Figure 2	3.0V to 3.6V	=	5.9	11.9	1.0	13.5	1.0	15.0				
t _{PD}	STCP to Qn	$C_L = 15pF$	4.5V to 5.5V	_	4.2	7.4	1.0	8.5	1.0	10.5				
Propagation Delay	STOPLOQII	Figure 2	3.0V to 3.6V	_	7.7	15.4	1.0	17.0	1.0	18.5	ns			
Belay		$C_L = 50pF$	4.5V to 5.5V	_	5.5	9.0	1.0	10.5	1.0	11.5				
		Figure 2	3.0V to 3.6V	_	5.9	12.8	1.0	13.7	1.0	15.0				
		$C_L = 15pF$	4.5 V to 5.5V	_	4.4	8.0	1.0	9.1	1.0	10.5				
	MR to Q7S	Figure 2	3.0V to 3.6V	_	7.4	16.3	1.0	17.2	1.0	18.7	ns			
		$C_L = 50pF$	4.5V to 5.5V	_	5.6	10.0	1.0	11.1	1.0	12.0				
		Figure 2	3.0V to 3.6V	=	5.6	11.5	1.0	13.5	1.0	15.0				
t _{EN}		$C_L = 15pF$	4.5V to 5.5V	=	4.0	8.6	1.0	10.0	1.0	0 10.5				
Enable Time	ime OE to Qn	Figure 2	3.0V to 3.6V	=	7.4	15.0	1.0	17.0	1.0	18.5	ns			
		$C_L = 50pF$	4.5V to 5.5V	-	5.3	10.6	1.0	12.0	1.0	13.0				
		Figure 2	3.0V to 3.6V	-	5.4	11.0	1.0	13.0	1.0	14.5				
t _{DIS}		C _L = 15pF	4.5V to 5.5V	-	3.8	8.0	1.0	9.5	1.0	10.5	_			
Disable Time	OE to Qn	Figure 2	3.0V to 3.6V	-	8.7	15.7	1.0	16.2	1.0	17.5	ns			
		C _L = 50pF	4.5V to 5.5V	=	5.8	10.3	1.0	11.0	1.0	12.0				

Operating Characteristics (@T_A = +25°C, unless otherwise specified.)

	Parameter	Test Conditions	V _{CC} = 5V Typ	Unit
$C_{\sf pd}$	Power dissipation capacitance	f = 1 MHz all outputs switching-no load	42	pF

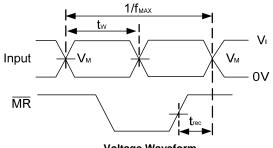


Parameter Measurement Information

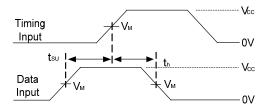


TEST	Vload
t _{PLH} /t _{PHL}	Open
t _{PLZ} /t _{PZL}	Vcc
t _{PHZ} /t _{PZH}	GND

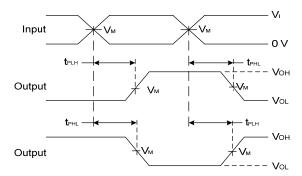
Vcc	Inp	outs	V	C.	
VCC	VI	t _r /t _f	V _M	C _L	
3.3V -3.6V	Vcc	3ns	V _{CC} /2	15pF, 50pF	
4.5V to 5.5V	V _{CC}	3ns	V _{CC} /2	15pF, 50pF	



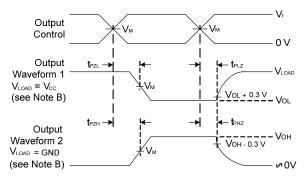
Voltage Waveform Pulse Duration and Recovery Time



Voltage Waveform Set-up and Hold Times



Voltage Waveform
Propagation Delay Times
Inverting and Non Inverting Outputs



Voltage Waveform Enable and Disable Times

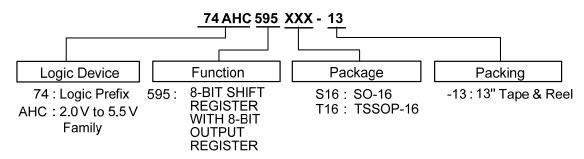
Notes: A .Includes test lead and test apparatus capacitance.

- B. Output Waveform 1 depends on the internal Q_N node being low and behaves in this manner based on OE pin. Output Waveform 2 depends on the internal Q_N node being high and behaves in this manner based on OE pin.
- C. All pulses are supplied at pulse repetition rate ≤ 10 MHz
- D. Inputs are measured separately one transition per measurement
- E. t_{PLH} and t_{PHL} are the same as $t_{\text{PD.}}$

Figure 2. Load Circuit and Voltage Waveforms



Ordering Information

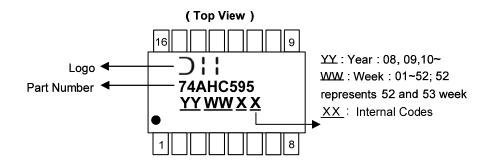


Part Number	Package Code Packaging		Backage Code	Packaging	7" Tape and	Reel (Note 6)
Fait Number	Package Code	rackaging	Quantity	Part Number Suffix		
74AHC595S16-13	S16	SO-16	2500/Tape & Reel	-13		
74AHC595T16-13	T16	TSSOP-16	2500/Tape & Reel	-13		

Note: 6. The taping orientation is located on our website at http://www.diodes.com/datasheets/ap02007.pdf

Marking Information

(1) SO-16, TSSOP16



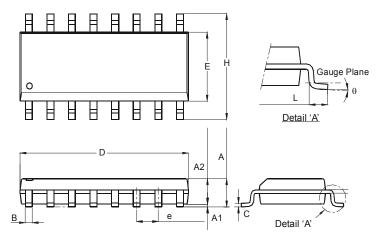
Part Number	Package
74AHC595S16	SO-16
74AHC595T16	TSSOP-16



Package Outline Dimensions (All dimensions in mm.)

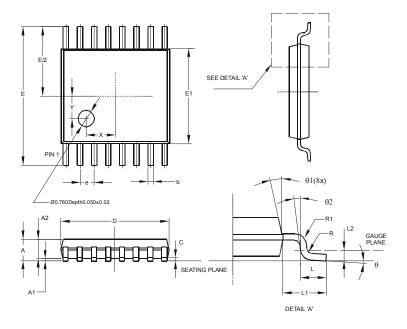
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.

Package Type: SO-16



SO-16						
Dim	Min	Max				
Α	1.40	1.75				
A1	0.10	0.25				
A2	1.30	1.50				
В	0.33	0.51				
С	0.19	0.25				
D	9.80	10.00				
Е	3.80	4.00				
е	1.27	Тур				
H	5.80	6.20				
L	0.38	1.27				
Θ	0°	8°				
All D	All Dimensions in mm					

Package Type: TSSOP-16



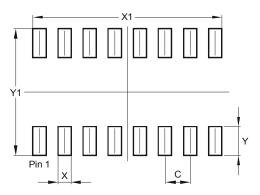
TSSOP-16				
Dim	Min	Max	Тур	
Α	-	1.08	-	
A1	0.05	0.15	-	
A2	0.80	0.93	-	
b	0.19	0.30	-	
U	0.09	0.20	1	
ם	4.90	5.10	1	
Е	6.40 BSC			
E1	4.30	4.50	-	
е	0.65 BSC			
L	0.45	0.75	-	
L1	1.00 REF			
L2	0.25 BSC			
R	0.09	ı	1	
R1	0.09	-	-	
X	ı	ı	1.350	
Υ	-	-	1.050	
Θ	0°	8°	-	
Θ1	5°	15°	-	
Θ2	0°	-	-	
All Dimensions in mm				



Suggested Pad Layout

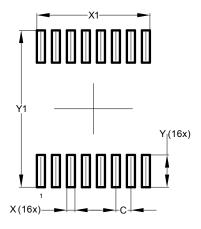
Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.

Package Type: SO-16



Dimensions	Value (in mm)	
С	1.270	
Х	0.670	
X1	9.560	
Y	1.450	
Y1	6.400	

Package Type: TSSOP-16



Dimensions	Value (in mm)	
С	0.650	
Х	0.350	
X1	4.900	
Y	1.400	
Y1	6.800	



IMPORTANT NOTICE

DIODES INCORPORATED MAKES NO WARRANTY OF ANY KIND, EXPRESS OR IMPLIED, WITH REGARDS TO THIS DOCUMENT, INCLUDING, BUT NOT LIMITED TO, THE IMPLIED WARRANTIES OF MERCHANTABILITY AND FITNESS FOR A PARTICULAR PURPOSE (AND THEIR EQUIVALENTS UNDER THE LAWS OF ANY JURISDICTION).

Diodes Incorporated and its subsidiaries reserve the right to make modifications, enhancements, improvements, corrections or other changes without further notice to this document and any product described herein. Diodes Incorporated does not assume any liability arising out of the application or use of this document or any product described herein; neither does Diodes Incorporated convey any license under its patent or trademark rights, nor the rights of others. Any Customer or user of this document or products described herein in such applications shall assume all risks of such use and will agree to hold Diodes Incorporated and all the companies whose products are represented on Diodes Incorporated website, harmless against all damages.

Diodes Incorporated does not warrant or accept any liability whatsoever in respect of any products purchased through unauthorized sales

Should Customers purchase or use Diodes Incorporated products for any unintended or unauthorized application, Customers shall indemnify and hold Diodes Incorporated and its representatives harmless against all claims, damages, expenses, and attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized application.

Products described herein may be covered by one or more United States, international or foreign patents pending. Product names and markings noted herein may also be covered by one or more United States, international or foreign trademarks.

This document is written in English but may be translated into multiple languages for reference. Only the English version of this document is the final and determinative format released by Diodes Incorporated.

LIFE SUPPORT

Diodes Incorporated products are specifically not authorized for use as critical components in life support devices or systems without the express written approval of the Chief Executive Officer of Diodes Incorporated. As used herein:

- A. Life support devices or systems are devices or systems which:
 - 1. are intended to implant into the body, or
 - 2. support or sustain life and whose failure to perform when properly used in accordance with instructions for use provided in the labeling can be reasonably expected to result in significant injury to the user.
- B. A critical component is any component in a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or to affect its safety or effectiveness.

Customers represent that they have all necessary expertise in the safety and regulatory ramifications of their life support devices or systems, and acknowledge and agree that they are solely responsible for all legal, regulatory and safety-related requirements concerning their products and any use of Diodes Incorporated products in such safety-critical, life support devices or systems, notwithstanding any devices- or systems-related information or support that may be provided by Diodes Incorporated. Further, Customers must fully indemnify Diodes Incorporated and its representatives against any damages arising out of the use of Diodes Incorporated products in such safety-critical, life support devices or systems.

Copyright © 2013. Diodes Incorporated

www.diodes.com

10 of 10 74AHC595 June 2013 © Diodes Incorporated Document number: DS35486 Rev. 3 - 2

单击下面可查看定价,库存,交付和生命周期等信息

>>Diodes Incorporated(达迩科技(美台))